

**400V NPN MEDIUM POWER HIGH VOLTAGE TRANSISTOR IN SOT23F**
**Features**

- $BV_{CEX} > 450V$
- $BV_{CEO} > 400V$
- $BV_{ECO} > 6V$
- $I_C = 0.5A$  Continuous Collector Current
- Low Saturation Voltage  $V_{CE(SAT)} < 175mV @ 500mA$
- 1.5W Power Dissipation
- Complementary PNP Type: ZXTP08400BFF
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Description**

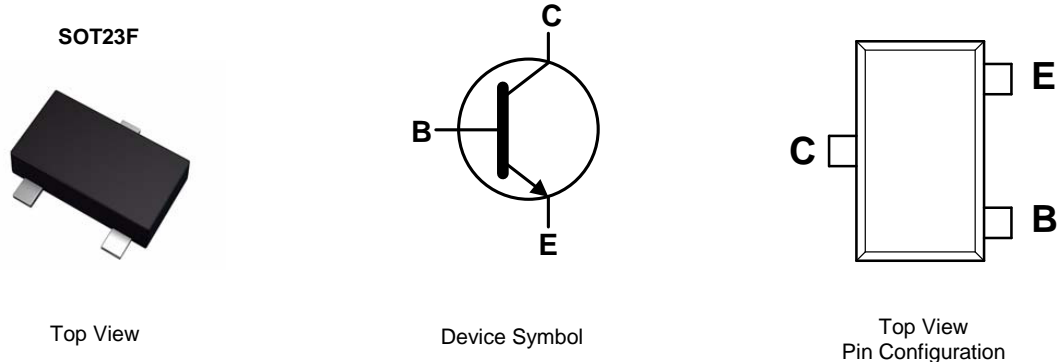
This NPN transistor has been designed for applications requiring high voltage blocking. The SOT23F package is pin compatible with the industry standard SOT23 foot print but offers lower profile and higher power dissipation for applications where power density is of utmost importance.

**Mechanical Data**

- Case: SOT23F
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.012 grams (Approximate)

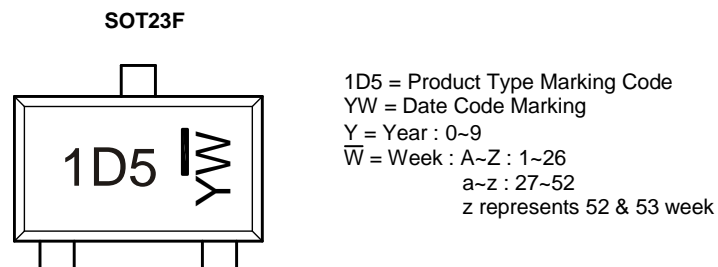
**Applications**

- High Voltage
- Low Saturation Voltage
- Low Profile Small Package Outline


**Ordering Information (Note 4)**

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTN08400BFFTA	AEC-Q101	1D5	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	450	V
Collector-Emitter Voltage (Forward Blocking)	V <sub>CEx</sub>	450	V
Collector-Emitter Voltage	V <sub>CEO</sub>	400	V
Emitter-Collector Voltage (Reverse Blocking)	V <sub>ECO</sub>	6	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	I <sub>C</sub>	0.5	A
Peak Pulse Current	I <sub>CM</sub>	1	A
Base Current	I <sub>B</sub>	0.2	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

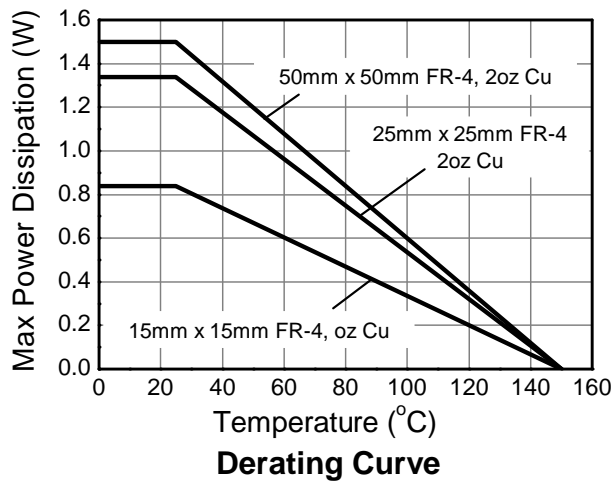
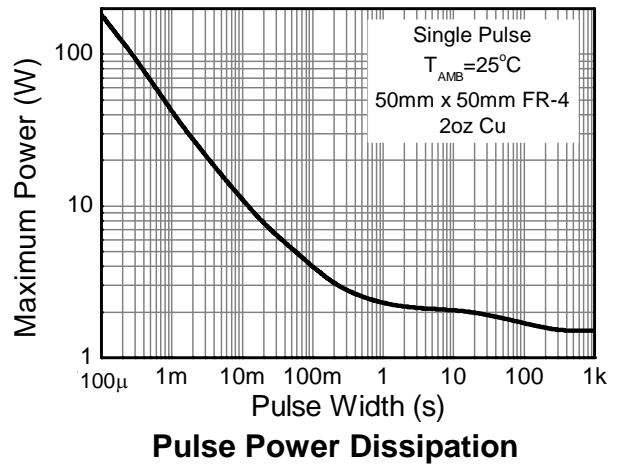
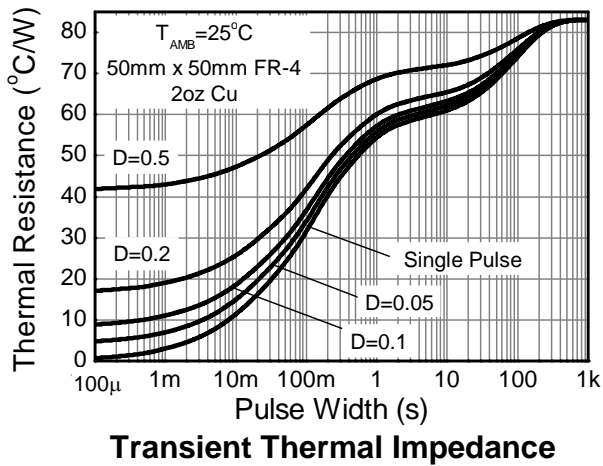
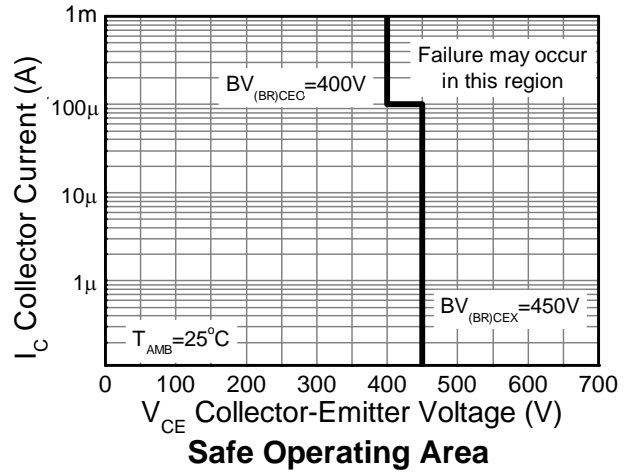
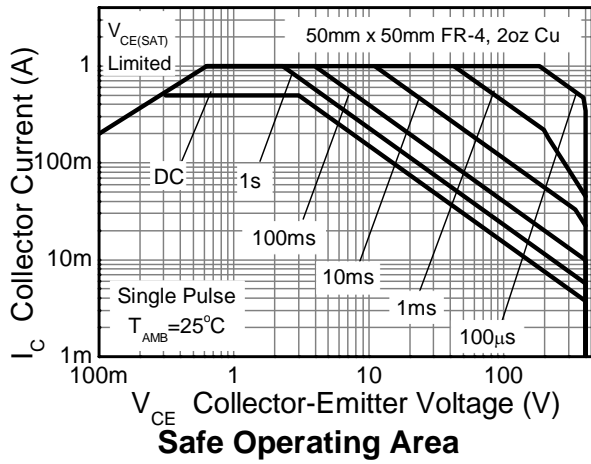
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P <sub>D</sub>	0.84	W mW/°C
		(Note 5)	
		6.72	
		(Note 6)	
		1.34	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	10.72	°C/W
		(Note 7)	
		1.5	
		12	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	2	°C/W
		(Note 8)	
		16	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	149	°C
		(Note 5)	
		93.4	
		(Note 6)	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	83.3	°C/W
		(Note 7)	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	60	°C/W
		(Note 8)	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	43.8	°C
		(Note 9)	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C
		(Note 9)	

**ESD Ratings** (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
  - Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
  - Same as Note 7, whilst measured at t < 5 seconds.
  - Thermal resistance from junction to solder-point (at the end of the collector lead).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

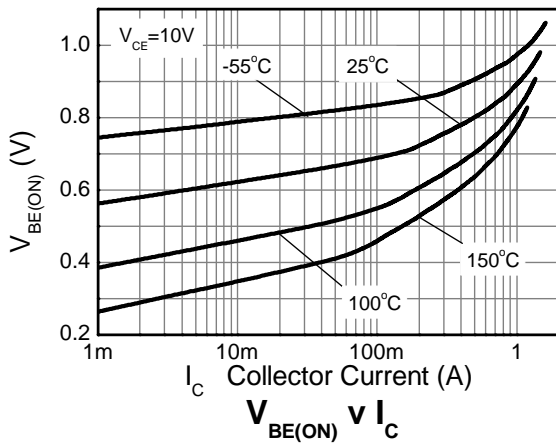
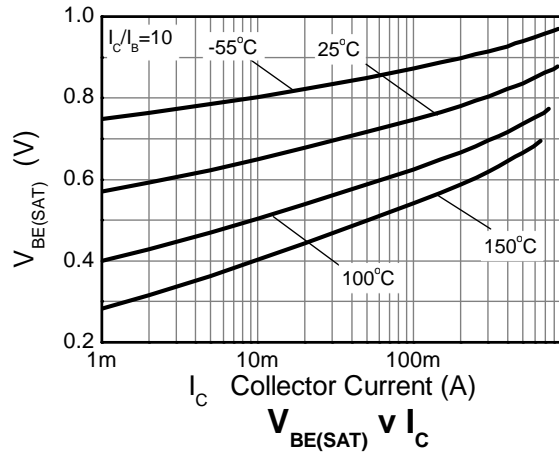
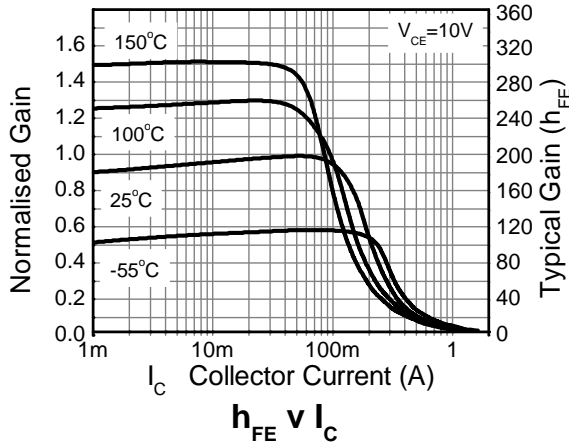
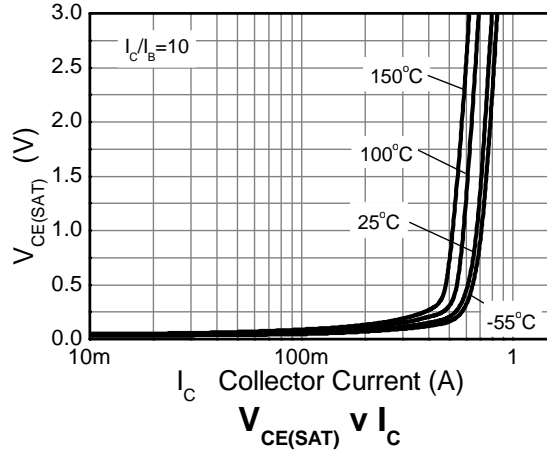
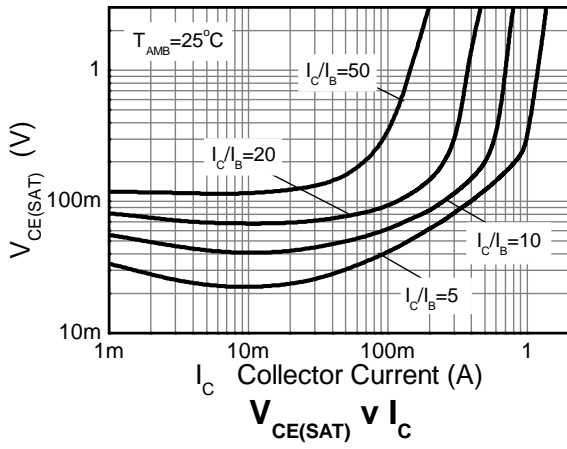


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	450	550	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Forward Blocking)	BV <sub>CEX</sub>	450	550	—	V	I <sub>C</sub> = 100μA, R <sub>BE</sub> ≤ 1kΩ or -1V < V <sub>BE</sub> < 0.25V
Collector-Emitter Breakdown Voltage (Base Open) (Note 11)	BV <sub>CEO</sub>	400	500	—	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.1	—	V	I <sub>E</sub> = 100μA
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV <sub>ECX</sub>	6	8	—	V	I <sub>E</sub> = 100μA, R <sub>BC</sub> ≤ 1kΩ or -0.25V < V <sub>BC</sub> < 0.25V
Emitter-Collector Breakdown Voltage (Base Open)	BV <sub>EEO</sub>	6	8.5	—	V	I <sub>E</sub> = 100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	—	<1	50	nA	V <sub>CB</sub> = 360V
Collector-Emitter Cutoff Current	I <sub>CEX</sub>	—	<1	100	nA	V <sub>CE</sub> = 360V, R <sub>BE</sub> ≤ 1kΩ
Emitter-Base Cutoff Current	I <sub>EBO</sub>	—	<1	50	nA	V <sub>EB</sub> = 5.6V
<b>ON CHARACTERISTICS</b> (Note 11)						
Static Forward Current Transfer Ratio	h <sub>FE</sub>	90 100 10	165 180 20	300	—	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V I <sub>C</sub> = 50mA, V <sub>CE</sub> = 5V I <sub>C</sub> = 500mA, V <sub>CE</sub> = 5V
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	—	70 50 120 125	85 70 170 175	mV	I <sub>C</sub> = 20mA, I <sub>B</sub> = 1mA I <sub>C</sub> = 50mA, I <sub>B</sub> = 5mA I <sub>C</sub> = 300mA, I <sub>B</sub> = 30mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 100mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	—	865	950	mV	I <sub>C</sub> = 500mA, I <sub>B</sub> = 100mA
Base-Emitter On Voltage	V <sub>BE(ON)</sub>	—	800	900	mV	I <sub>C</sub> = 500mA, V <sub>CE</sub> = 10V
<b>SMALL SIGNAL CHARACTERISTICS</b> (Note 11)						
Transition Frequency	f <sub>T</sub>	—	40	—	MHz	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 20V, f = 20MHz
Output Capacitance	C <sub>OBO</sub>	—	8	10	pF	V <sub>CB</sub> = 20V, f = 1MHz
Delay Time	t <sub>D</sub>	—	100	—	ns	V <sub>CC</sub> = 100V, I <sub>C</sub> = 100mA, I <sub>B1</sub> = 10mA I <sub>B2</sub> = -20mA
Rise Time	t <sub>R</sub>	—	52	—	ns	
Storage Time	t <sub>S</sub>	—	3122	—	ns	
Fall Time	t <sub>F</sub>	—	240	—	ns	

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

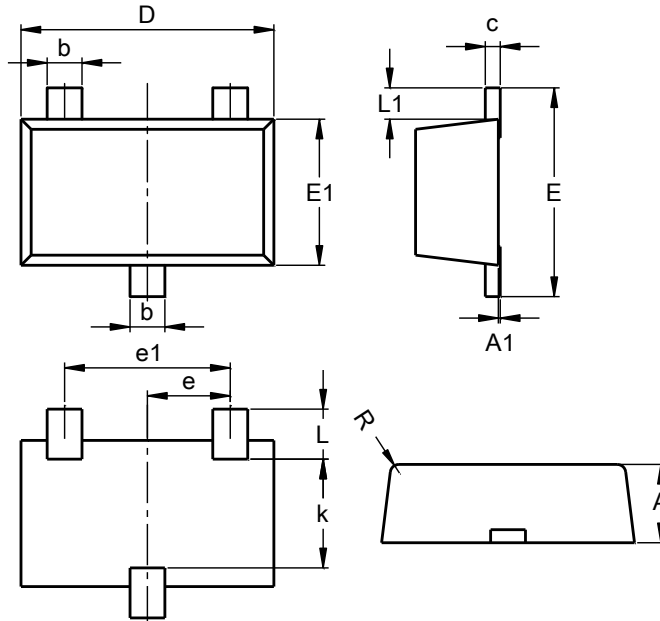
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23F**

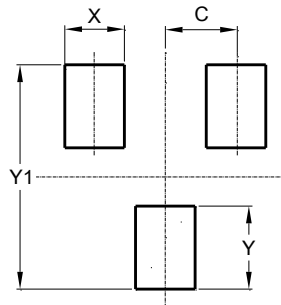


SOT23F			
Dim	Min	Max	Typ
A	0.80	1.00	0.90
A1	0.00	0.10	0.01
b	0.35	0.50	0.44
c	0.10	0.20	0.16
D	2.80	3.00	2.90
e	0.95 REF		
e1	1.90 REF		
E	2.30	2.50	2.40
E1	1.50	1.70	1.65
k	1.20	-	-
L	0.30	0.65	0.50
L1	0.30	0.50	0.40
R	0.05	0.15	-
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23F**



Dimensions	Value (in mm)
C	0.95
X	0.80
Y	1.110
Y1	3.000

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